

SMC660

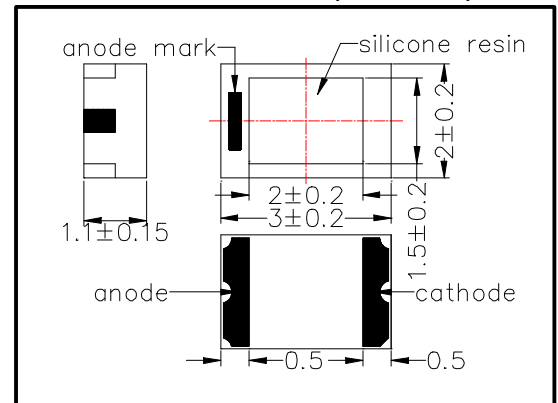
High Bright Red color SMD LED on ceramics

SMC660 consists of an AlGaAs LED mounted on the ceramics package and is sealed with silicone or epoxy resin. It emits a spectral band of radiation at 660nm.

Specifications

- | | |
|---------------------|-------------------------|
| 1) Product Name | SMD type red color LED |
| 2) Type No. | SMC660 |
| 3) Chip | |
| (1) Chip Material | AlGaAs |
| (2) Peak Wavelength | 660nm typ. |
| 4) Package | |
| (1) Package | Ceramics |
| (2) Lens | Silicone or Epoxy resin |

Outer dimension (Unit : mm)



Absolute Maximum Ratings

Item	Symbol	Maximum Rated Value	Unit	Ambient Temperature
Power Dissipation	P_D	120	mW	$T_a=25^\circ\text{C}$
Forward Current	I_F	50	mA	$T_a=25^\circ\text{C}$
Reverse Voltage	V_R	5	V	$T_a=25^\circ\text{C}$
Operating Temperature	T_{OPR}	$-20 \sim +80$	$^\circ\text{C}$	
Storage Temperature	T_{STG}	$-30 \sim +80$	$^\circ\text{C}$	
Soldering Temperature	T_{SOL}	240	$^\circ\text{C}$	

‡Soldering condition: Soldering condition must be completed within 3 seconds at 240°C

Electro-Optical Characteristics [$T_a=25^\circ\text{C}$]

Item	Symbol	Condition	Minimum	Typical	Maximum	Unit
Forward Voltage	V_F	$I_F=20\text{mA}$		1.90	2.30	V
Reverse Current	I_R	$V_R=5\text{V}$			10	μA
Total Radiated Power	P_O	$I_F=20\text{mA}$		2.5		mW
Brightness	I_v	$I_F=20\text{mA}$	40	80		mcd
Peak Wavelength	λ_P	$I_F=20\text{mA}$	650	660	670	nm
Half Width	$\Delta\lambda$	$I_F=20\text{mA}$		20		nm
Viewing Half Angle	$\theta_{1/2}$	$I_F=20\text{mA}$		± 55		deg.

‡Total Radiated Power is measured by Photodyne #500

‡Brightness is measured by Tektronix J-16.

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